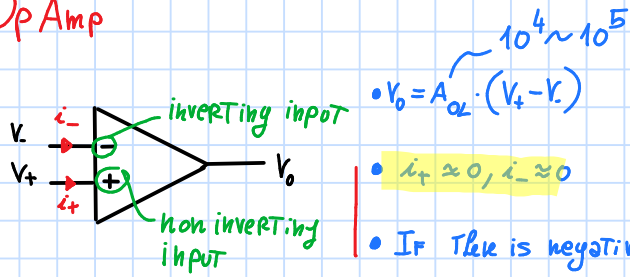
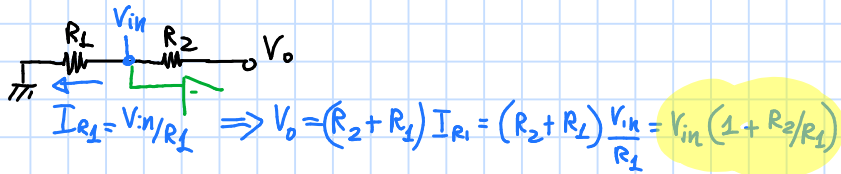
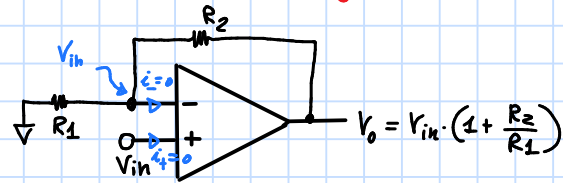


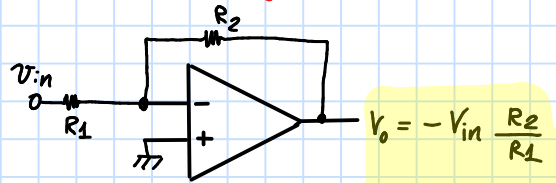
# Op Amp



## Non inverting Configuration

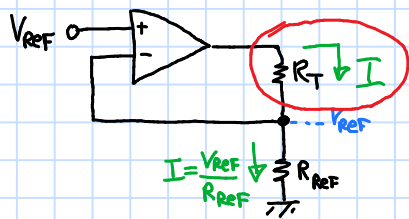


## Inverting Configuration

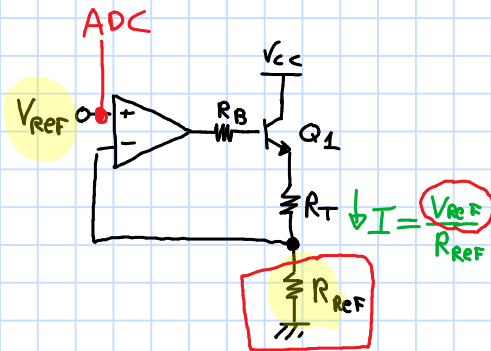


## Website:

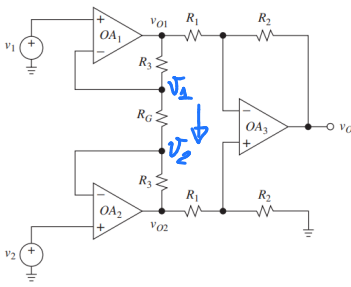
## → CURRENT GENERATOR



⇒



# Instrument Amplifier (INA)



- $V_o = G \cdot (V_2 - V_1)$

$$G = \left(1 + \frac{2R_3}{R_G}\right) \frac{R_2}{R_1}$$

LM358  $\approx 0,4\text{€}$

AD623  $\approx 5\text{€}/\text{chip}$

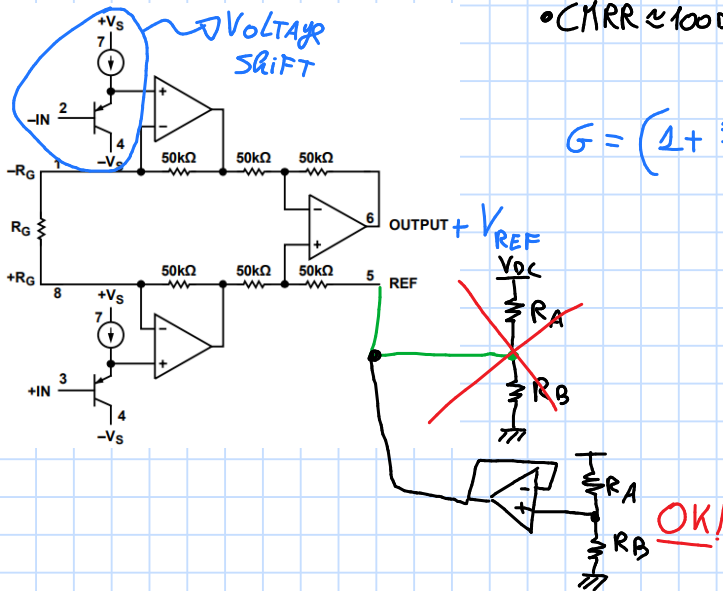
- Differential voltage:  $V_D = V_2 - V_1$

- Common Mode voltage:  $V_{CM} = \frac{V_2 + V_1}{2}$

$$V_o = \frac{G}{A_D} \cdot V_D + A_{CM} \cdot V_{CM}$$

- $CMRR_{dB} = 20 \cdot \log_{10} \left( \frac{A_D}{A_{CM}} \right)$   
 $\uparrow$   
 $\approx 100\text{ dB}$   
 AD623

• AD623

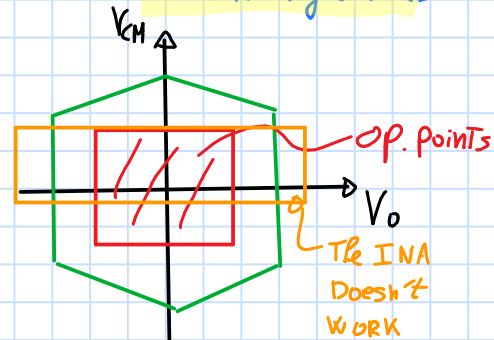


- $CMRR \approx 100\text{ dB}$

$$G = \left(1 + \frac{100k\Omega}{R_G}\right)$$

- Operating Limit

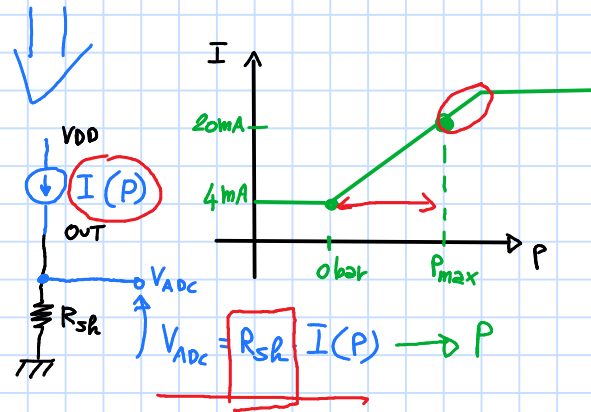
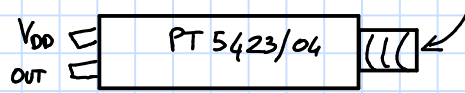
→ Tool: Diamond Plot  
From Analog Devices



## • Pressure Sensor

- PT5402 (100 bar)
- PT5423 (60 bar)

From iFm



$$I(P) = 20 \text{ mA} \Rightarrow V_{ADC} = 3,3 \text{ V} \Rightarrow R_{sh} = \frac{V_{ADC}}{I(P)} = 165 \Omega$$

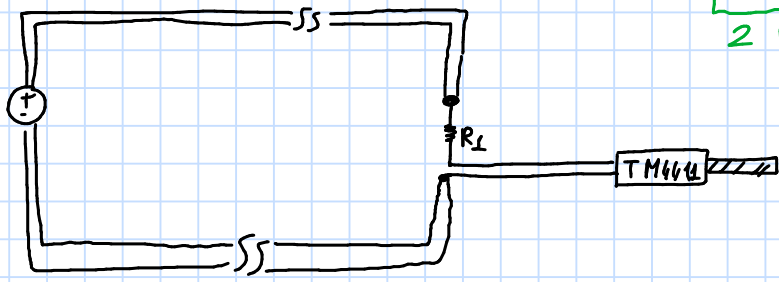
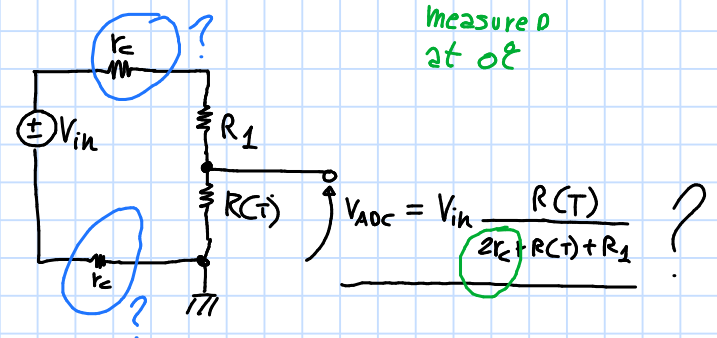
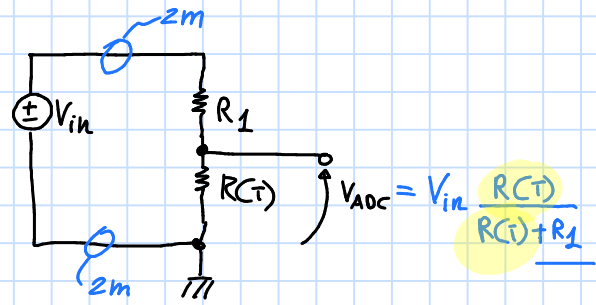
$$P_R = R_{sh} \cdot I(P)^2 = \underline{0,066 \text{ W}}$$

# Temperature Sensor

- TM4411 (~100€) + Precise, + reliability
  - NBPTCO-176 (~2€) → 2 wires
- 4 wires sensor  
 $T_{MAX} \approx 150^\circ C$   
 100 bar max

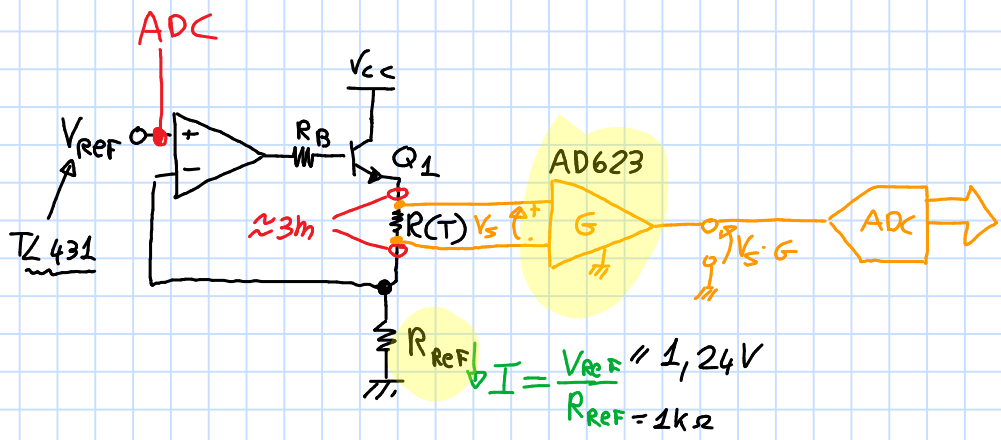
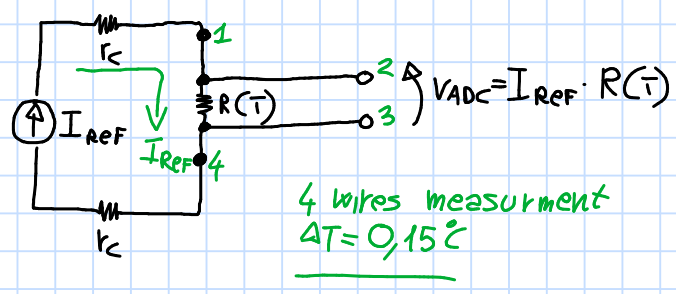
$$R(T) = R_0 [1 + \alpha T]$$

Resistance measure 0 at 0°  
 3850 ppm

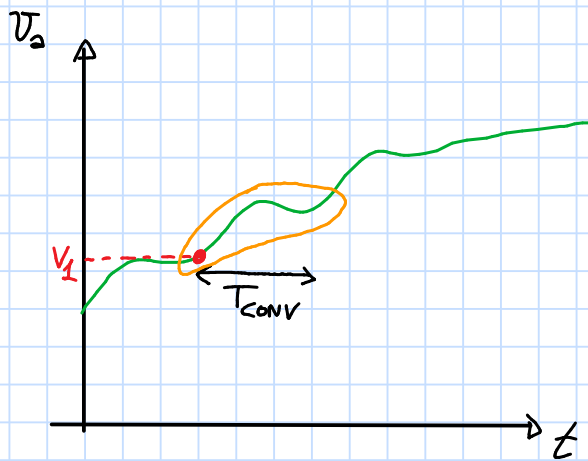


2 wires measurement  $\Delta T = T_{meas} - T_{real} \approx 2^\circ C$

→ 4 wire measurement

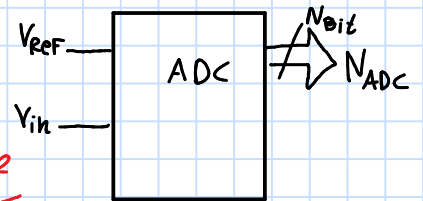


# Note on ADC

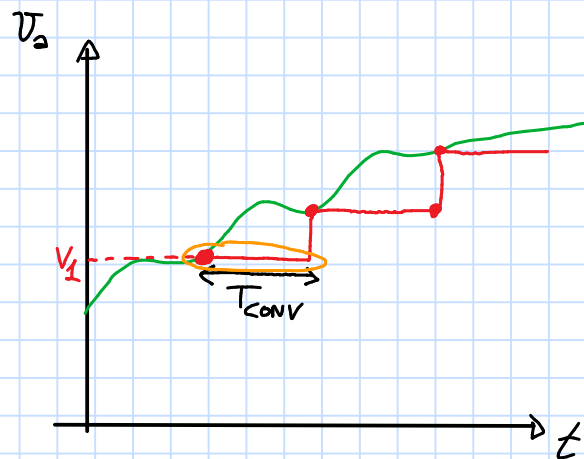
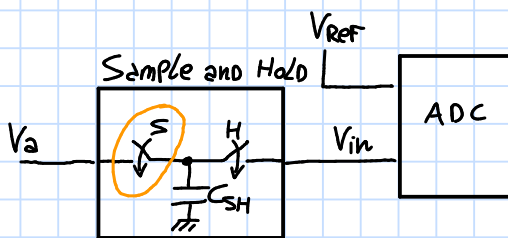


ADC  $\Rightarrow$

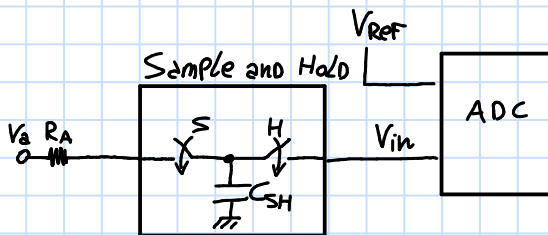
$$N_{ADC}(V_{in}) = V_{in} \cdot \frac{2^{12}}{V_{REF}}$$



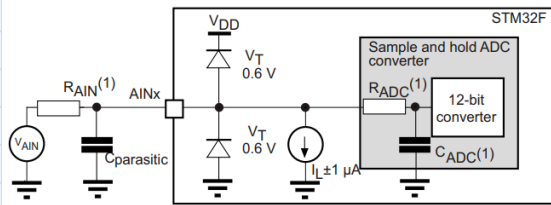
## • Sample and Hold



• On STM32 It's possible to select the Time interval in which S is closed



$$\tau = R_A \cdot C_{SH}$$



$$f_{clk} = 25 \text{ MHz}$$

$$T_{conv} = 15 \text{ ADC clock cycles}$$

$$T_{smp} = 28 \text{ "}$$

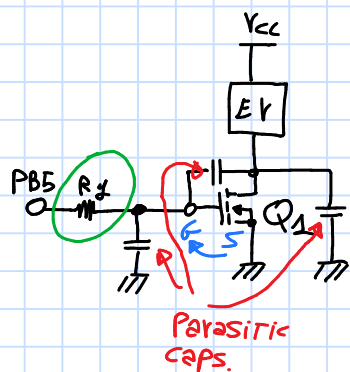
$$C_{ADC} \approx 7 \text{ pF} \quad R_{ADC} = 6 \text{ K}\Omega$$

Equation 1:  $R_{AIN}$  max formula

$$R_{AIN} = \frac{(k - 0.5)}{f_{ADC} \times C_{ADC} \times \ln(2^{N+2})} - R_{ADC}$$

The formula above (Equation 1) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB.  $N = 12$  (from 12-bit resolution) and  $k$  is the number of sampling periods defined in the ADC\_SMPR1 register.

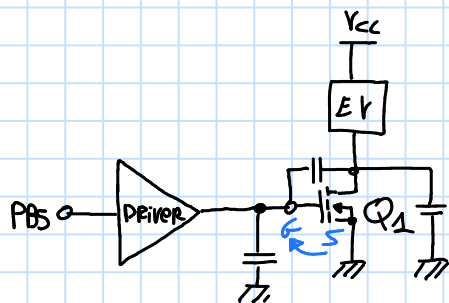
# Note on Power Electronic



•  $Q_1$  Turns on if  $V_{GS} > V_{TR}$

✓ Rarely Turn on/OFF

✓ if you have a lot of time to turn on the MOSFET

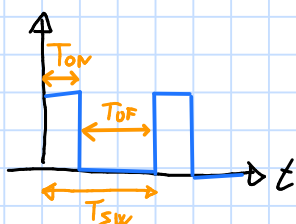
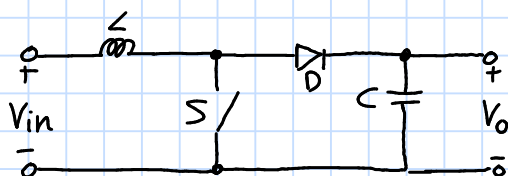
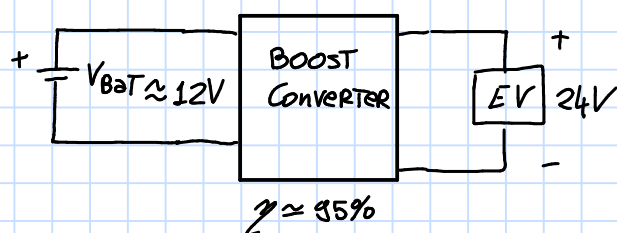


• Ix01602

✓ Turn on/off Frequently

✓ Time Constraints

• Supply voltage For EV



$$T_{sw} = T_{on} + T_{off}$$

$$D = \frac{T_{on}}{T_{sw}} \text{ (Duty cycle)}$$

$$T_{EV} = 250 \text{ ms}$$

$$I_{EV} = 3 \text{ A} \Rightarrow I_{cap} = 1 \text{ A}$$

$$C = \frac{1}{\frac{1}{C} \cdot \frac{dV_c}{dt}} \Rightarrow V_c = \frac{1}{C} \int i_c \cdot dt = \frac{I_{cap} \cdot T_{EV}}{C}$$

$$\Rightarrow C = \frac{I_{cap} \cdot T_{EV}}{\Delta V} = \frac{1 \text{ A} \cdot 250 \text{ ms}}{1 \text{ V}} = 250 \text{ mF}$$

• First Design

$$V_{in} \in [6-12] \text{ V}$$

$$V_o = 24 \text{ V}$$

$$P \approx 50 \text{ W}$$

• Second Design

$$V_{in} \in [10-15] \text{ V}$$

$$V_o = 24 \text{ V}$$

$$P_o = 120 \text{ W}$$

$$V_o = \frac{1}{1-D} \cdot V_{in}$$

→ It's Too Big